NSN 5961-01-589-4827

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View Online at https://aerobasegroup.com/nsn/5961-01-589-4827 **Inclosure Material:** Glass **Overall Length:** Between 2.155 inches and 3.155 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.060 inches and 0.090 inches **Function For Which Designed:** Zener diode **End Application:** 5841-01-552-8119 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Terminal Circle Diameter:** 0.020 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.1 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 47.00 milliamperes dc current in reverse breakdown region **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/533 government specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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Mil-std (military Standard):

Mil-prf-19500 spec.